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### APPLICANTS

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### \*\* CONTINUING DATA \*\*\*\*\*

This application is a DIV of 09/931,915 08/20/2001 PAT 6,617,627 CW

### \*\* FOREIGN APPLICATIONS \*\*\*\*\*

JAPAN 2000-251436 08/22/2000 CW

### IF REQUIRED, FOREIGN FILING LICENSE GRANTED

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Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no	STATE OR	SHEETS	TOTAL	INDEPENDENT
35 USC 119 (a-d) conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance	COUNTRY	DRAWING	CLAIMS	CLAIMS
Verified and Acknowledged Examiner's Signature <i>[Signature]</i> Initials <i>[Initials]</i>	JAPAN	13	20	3

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### TITLE

Memory cell array having ferroelectric capacity, method of manufacturing the same and ferroelectric memory device

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